

SOT-523

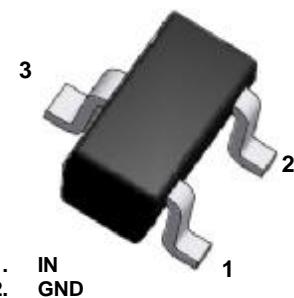
Digital Transistor (Built-in Resistors) PNP Silicon Surface Mount Transistor

Green Product

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-base Voltage	-50	V
V_{CEO}	Collector-emitter Voltage	-50	V
V_{EBO}	Emitter-base Voltage	-5	V
I_C	Collector Current	-100	mA
P_D	Power Dissipation	150	mW
T_J	Junction to Ambient	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$

These ratings are limiting values above which the serviceability of the device may be impaired.

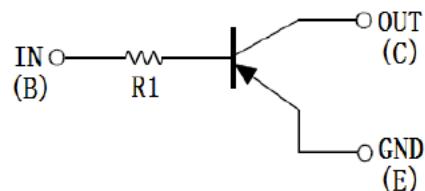


SOT-523 (SC-75A)

FEATURES:

- § Built-in resistors enable the configuration of a inverter circuit without connecting external input resistors.
- § The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- § Only the on/off conditions need to be set for operation, making device design easy.
- § RoHS Compliant
- § Green EMC
- § Matte Tin(Sn) Lead Finish
- § Weight: approx. 0.002g

ELECTRICAL SYMBOL:

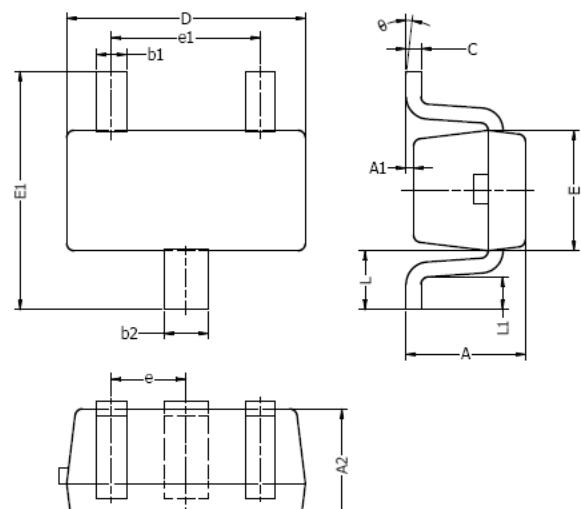


DEVICE MARKING CODE:

Device Type	Device Marking
DTA143TE	93

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Limits			Unit
			Min	Typ	Max	
Collector-base breakdown Voltage	$\mathbf{BV}_{\mathbf{CBO}}$	$I_C = -50\mu\text{A}, I_E = 0$	-50			V
Collector-emitter breakdown Voltage	$\mathbf{BV}_{\mathbf{CEO}}$	$I_C = -1\text{mA}, I_B = 0$	-50			V
Emitter-base breakdown Voltage	$\mathbf{BV}_{\mathbf{EBO}}$	$I_E = -50\mu\text{A}, I_C = 0$	-5			V
Collector cut-off Current	$I_{\mathbf{CBO}}$	$V_{CB} = -50\text{V}, I_E = 0$			-0.5	μA
Emitter cut-off Current	$I_{\mathbf{EBO}}$	$V_{EB} = -4\text{V}, I_C = 0$			-0.5	μA
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = -5\text{mA}, I_B = 0.25\text{mA}$			-0.3	V
DC current gain	h_{FE}	$V_{CE} = -5\text{V}, I_C = -1\text{mA}$	100	250	600	
Input Resistance	R_I		3.29	4.7	6.11	$\text{k}\Omega$
Transition Frequency	f_T	$V_{CE} = -10\text{V}, I_E = -5\text{mA}$ $f=100\text{MHz}$		250		MHz

SOT-523 Package Outline


DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.70	0.90	0.028	0.035
A1	0.00	0.10	0.000	0.004
A2	0.70	0.80	0.028	0.031
b1	0.15	0.25	0.006	0.010
b2	0.25	0.35	0.010	0.014
c	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
E1	1.45	1.75	0.057	0.069
e	0.50 TYP.		0.020 TYP.	
e1	0.90	1.10	0.035	0.043
L	0.40 REF.		0.016 REF.	
L1	0.10	0.30	0.004	0.012
θ	0°	8°	0°	8°

NOTES:

1. Above package outline conforms to JEITA EAJ ED-7500A SC-75A.
2. Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.

Typical Soldering Pattern:
